



(Top View)

ΕP

U-DFN3030-10

Pin 1 Mark

AP3436/A

10 EN

- a

8

6

PGOOD

BOOT

sw

SW

3A, 1.25MHZ HIGH PERFORMANCE SYNCHRONOUS BUCK CONVERTER

Pin Assignments

FB

VCC

VIN

GND

GND

Features

2

3

5

Analog Power Input Vcc Range: 3.0V to 5.5V

0.6V Reference Voltage with ±1.5% Precision

2 MOSFETs (Typ 50mΩ) for High Efficiency at 3A Loads

Power Input VIN Range: 1.3V to 5.5V

Built-in UV and OV Protection Function

Thermally Enhanced 3mm×3mm DFN Package

Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2) Halogen and Antimony Free. "Green" Device (Note 3)

Built-in Over Current Protection

Built-in Thermal Shutdown Function

High Efficiency: Up to 95%

Built-in Soft Start Function UV and OV Power Good Output

Output Current: 3A

Current Mode Control

Description

The AP3436/A is a step-down DC-DC converter with integrated power stage capable of driving up to 3A continuous output current. It integrates 2 N-channel power MOSFETs with low on-resistance. Current mode control provides fast transient response and cycle-by-cycle current limit.

For AP3436, the regulator adopts current-mode in forced pulse-width modulation (PWM) mode with 1.25MHz switching frequency internally, which allows small-sized components, such as capacitors and inductors. This feature greatly simplifies the design of switch-mode power supplies. Under PWM mode, the device remains at the fixed PWM operation (typical at 1.25MHz), regardless of if the load current is high or low.

For AP3436A, the regulator operates in either fixed PWM mode or a pulse-skipping modulation (PSM) mode depending on the different load conditions. The device can operate at typical 1.25MHz fixed switching frequency under heavy load condition. At light load, the regulator enters a PSM mode to minimize the switching loss by reducing the switching frequency.

The AP3436/A provides EN function. Pulling this pin high statically enables the device while pulling the pin low statically for longer than 10µs will shut it down.

Under Voltage Lockout is internally set at 2.75V for V_{CC} detection. The output voltage startup ramp is controlled by the soft start. An open drain power good signal indicates the output is within 75% to 125% of its nominal voltage.

The AP3436/A is available in U-DFN3030-10 package.

Applications

- Desktop & Notebook
- Low Voltage, High Density Power System
- Consumer Application Such as Set Top Box, LCD Display and CPE Equipment

Notes:

- 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant.
 - See http://www.diodes.com/quality/lead_free.html for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
 - 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.



Typical Applications Circuit



Note 4: When using a single power supply for V_{CC} and V_{IN}, a 4,7Ω resistor should be placed between them for noise isolation.

Component	Value	Unit	Component	Value	Unit
Cvcc	1	μF	Cin	44	μF
Rpg	10	kΩ	Своот	0.1	μF
Rfb2	твр	kΩ	L1	1.5	μH
R _{FB1}	TBD	kΩ	Cout	88	μF

Table 1. Component Guide



Pin Descriptions

Pin Number	Pin Name	Function
1	FB	Voltage Feedback Input. Connect to VOUT through a voltage divider to set the output voltage
2	VCC	Analog Power Input
3	VIN	Power Input
4, 5	GND	Ground. Must be Connected to GND on PCB
6, 7	SW	Power Switch Output
8	BOOT	High Side Switch Driver Supply
9	PGOOD	Open Drain Power Good Output
10	EN	Enable
11	Exposed Pad	Thermal Connection to the PCB. Must be connected to GND on PCB

Functional Block Diagram





Absolute Maximum Ratings (Note 5)

Symbol	Parameter	Rating	Unit
V _{CC} , V _{IN}	VCC, VIN Pin Voltage	-0.3 to 6	V
Ven	EN Pin Voltage	-0.3 to 6	V
Vsw	SW Pin Voltage	-0.3 to VIN+0.3	V
VSW_TRANSIENT	SW Pin Transient Voltage (<50ns)	-5 to Vin+5	V
VFB	FB Pin Voltage	-0.3 to 6	V
V _{PGD}	PGOOD Pin Voltage	-0.3 to 6	V
VBOOT_SW	BOOT to SW Voltage	0 to 6	V
θја	Thermal Resistance (Junction to Ambient, Simulation)	33	°C/W
өлс	Thermal Resistance (Junction to Case)	3	°C/W
TJ	Operating Junction Temperature	-40 to +150	°C
T _{STG}	Storage Temperature	-65 to +150	°C
TLEAD	Lead Temperature (Soldering, 10sec)	+260	°C
V _{HBM}	ESD (Human Body Model)	2000	V
VMM	ESD (Machine Model)	200	V

Note 5: Stresses greater than those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "Recommended Operating Conditions" is not implied. Exposure to "Absolute Maximum Ratings" for extended periods may affect device reliability.

Recommended Operating Conditions

Symbol	Parameter	Min	Мах	Unit
Vcc	Analog Input Voltage	3.0	5.5	V
V _{IN}	Power Input Voltage	1.3	5.5	V
Ιουτ(ΜΑΧ)	Maximum Output Current	3	-	А
Vout	Output Voltage	0.8	Vin	V
Та	Operating Ambient Temperature	-40	+85	°C



Electrical Characteristics (V_{CC} = 5V, V_{IN} = 5V, T_A = +25°C, unless otherwise specified.)

Symbol	Parameter	Conditions	Min	Тур	Max	Unit	
SUPPLY VOLTAGE (VCC, VIN PIN)							
Vcc	Analog Power Input Voltage	-	3.0	_	5.5	V	
VIN	Power Input Voltage	-	1.3	-	5.5	V	
lq	Quiescent Current	VFB = 1.5V, Vcc = 5V, VIN = 5V	-	400	-	μA	
Ishdn	Shutdown Supply Current	$V_{EN} = 0V,$ $3.0V \le V_{CC} \le 5.5V,$ $1.3V \le V_{IN} \le 5.5V$	-	-	1	μA	
POWER ON RESET							
V _{UVLO}	Internal Under Voltage Lockout Threshold for V _{CC}	-	-	2.75	2.85	V	
VHYS_VCC	Internal Under Voltage Hysteresis for V_{CC}	-	-	150	-	mV	
VOLTAGE REFERENCE (FB PIN)						
VFB	Voltage Reference	$3.0V \le V_{CC} \le 5.5V$	0.591	0.600	0.609	V	
INTERNAL PWM FREQUE	ENCY						
f	PWM Frequency	$3.0V \le V_{CC} \le 5.5V$	1.0	1.25	1.5	MHz	
MOSFET SPEC							
2	High Side Switch On-resistance	VBOOT_SW = 5.0V	_	50	100	mΩ	
Ron_h		VBOOT_SW = 3.0V	_	70	140	mΩ	
_		Vcc = 5.0V	_	50	100	mΩ	
Ron_L	Low Side Switch On-resistance	$V_{CC} = 3.0V$	_	70	140	mΩ	
CURRENT LIMIT							
Ілміт	Current Limit Threshold	_	4.8	7.6	_	А	
THERMAL SHUTDOWN							
TTSD	Thermal Shutdown	-	_	+160	_	°C	
-	Hysteresis	-	_	+20	_	°C	
BOOT SPEC (BOOT PIN)							
Rвоот	BOOT Charge Resistor	Vcc = 5.0V	-	16	-	Ω	
	BOOT to SW UVLO	V _{CC} = 3.0V	-	2.2	-	V	
SOFT START				•	-	•	
tss	Soft Start Time	_	0.8	-	2	ms	



Electrical Characteristics (Cont. V_{CC} = 5V, V_{IN} = 5V, T_A = +25°C, unless otherwise specified.)

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
ENABLE (EN PIN)						
Ven_L		-	_	_	0.8	V
V _{EN_H}	EN Pin Threshold	_	1.6	-	-	V
POWER GOOD (PGOOD	PIN)					
		VFB falling (Fault)	70	75	-	%V _{RE} F
		VFB rising (Good)	77	82	-	
Vfbth	Feedback Threshold	VFB rising (Fault)	-	125	130	
		V _{FB} falling (Good)		118	123	
tpg_dly	Delay Time for PGOOD from High to Low	-	-	30	-	μs
Rpg	Internal Power Good Pull Low Resistance	-	-	-	150	Ω
Rpg_up	External Pull-up Resistance Range	-	3000	-	-	Ω
SYSTEM PERFORMANC	E					
VUVP	Output Under Voltage Protection Threshold	V _{IN} = 1.3 to 5.5V	_	_	0.5× V _{OUT}	V
tuvp	Delay Time for UVP Triggered	VIN = 1.5 to 5V	_	65	_	μs
Vovp	Output Over Voltage Protection Threshold	V _{IN} = 1.3 to 5.5V	1.5× Vouт	-	-	V
tovp	Delay Time for OVP Triggered	VIN = 1.5 to 5V	_	65	-	μs
Іоит	Output Current	V _{IN} = 1.5 to 5V, V _{OUT} = 1.0V	3	-	-	А
-	Output Voltage Line Regulation	V _{IN} = 1.5 to 5V, IOUT = 100mA	_	0.4	-	%× Vout/V
-	Output Voltage Load Regulation	IOUT = 0A to 3A	_	0.3	_	% × Vout/A
Vtran	Output Voltage Load Transient	V _{IN} = 5V, V _{OUT} = 1.0V, dl/dt = 400mA/µs	_	±2.5	_	% × Vout/A
η	Efficiency	Vcc = 5V, VIN=5V, IOUT = 3A, VOUT = 1.2V	-	80	-	%



Performance Characteristics



AP3436/A Document number: DS37212 Rev. 4 - 4

Temperature (°C)



Performance Characteristics (Cont.)



Load Regulation vs. Output Current





Line Regulation vs. Input Voltage



Power on Waveform (VIN=Vcc=5V, Vout=1V, Iout=3A)



Time 400µs/div

Enable Waveform (VIN=Vcc=5V, Vout=1V, Iout=3A)



Time 1ms/div



Performance Characteristics (Cont.)





Application Information

1. Overview

The AP3436/A is a 3A synchronous buck (step-down) converter with two integrated N-channel MOSFETs. For AP3436, the regulator operates in PWM mode with 1.25MHz switching frequency internally, regardless of if the load current is high or low. For AP3436A, when the load is very light, the regulator automatically operates in the PSM mode to minimize the switching loss, thus achieving high efficiency at light load. When the load increases, the regulator automatically switches over to a current-mode PWM operating at nominal 1.25MHz switching frequency.

2. Power On Reset

A Power On Reset (POR) circuitry continuously monitors the supply voltage at VCC pin. Once the rising POR threshold is exceeded, the AP3436/A sets itself to active state and is ready to accept chip enable command. The rising POR threshold is typically 2.75V.

3. Soft Start

A built-in soft-start is used to prevent surge current from power supply input V_{IN} during turn on (Referring to the Functional Block Diagram). The error amplifier is a three-input device. Reference voltage V_{REF} or the internal soft-start voltage V_{SS} whichever is smaller dominates the behavior of the non-inverting inputs of the error amplifier. V_{SS} internally ramps up to 0.6V after the soft-start cycle is initiated. The ramp is created digitally, so the output voltage will follow the V_{SS} signal and ramps up smoothly to its target level.

4. EN Function

The AP3436/A provides Enable Function. Pulling this pin higher than 1.6V statically enables the AP3436/A while pulling the pin lower than 0.8V statically for longer than 10µs will shutdown the IC.

5. Adjusting Output Voltage

The output voltage is set with a resistor divider from the FB pin. It is recommended to use divider resistors with 1% tolerance or better. Start with a $100k\Omega$ for the resistor R1 and use the following equation to calculate R2. Consider using larger value resistors to improve efficiency at very light loads. If the values are too high, the regulator is more susceptible to noise and the voltage errors caused by FB input current are noticeable.



6. Short Circuit Protection (SCP)

The AP3436/A has Over Current Protection (OCP) and Under Voltage Protection (UVP) functions.

6.1 OCP Function

The high side switch current is detected during each cycle. During SCP conditions, the output voltage is pulled down and the switch current is increased. Once the increased high side switching current is detected to trigger the current limit of high side switch, the high side switch will be immediately turned off and will not be turned on again until the next switching cycle. When over current condition is removed, the AP3436/A will recover back to normal operation again.

6.2 UVP Function

The FB voltage is also monitored for Under Voltage Protection. The UV threshold is set at 0.2V. The under voltage protection has 65µs triggered delay. When UVP is triggered, both high side and low side are shutdown immediately. The UVP is a latched function, reset power supply or EN pin to restart AP3436/A again.



Application Information (Cont.)

7. Over Voltage Protection (OVP)

The output voltage is continuously monitored for Over Voltage Protection by FB pin. When it is larger than 1.67 times as setting, the OVP function is triggered. The Over Voltage Protection has 65µs triggered delay.

When OVP is triggered, both high side and low side are shutdown immediately and the output voltage is discharged by an internal 1kΩ resistor.

8. Power Good

The PGOOD pin output connects an open drain MOSFET. The output is pulled low when the FB voltage enters the fault condition by falling below 75% or rising above 125% of the nominal internal reference voltage. There is a 7% hysteresis on the threshold voltage, so when the FB voltage rises to the good condition above 82% or falls below 118% of the internal voltage reference the PGOOD output MOSFET is turned off. It is recommended to use a pull-up resistor between the values of $3k\Omega$ and $100k\Omega$ to a voltage source that is 5V or less.

9. Thermal Shutdown

The device implements an internal thermal shutdown to protect itself if the junction temperature exceeds +160°C. Switching is stopped when the junction temperature exceeds the thermal trip threshold. Once the die temperature decreases below +140°C, the device reinitiates the soft start operation. The thermal shutdown hysteresis is +20°C.







Package Outline Dimensions (All dimensions in mm(inch).)

(1) Package Type: U-DFN3030-10





AP3436/A

Suggested Pad Layout

(1) Package Type: U-DFN3030-10





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